SI1553DL-T1-GE3-VB Datasheet

N-and P- Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY			
	V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)
N-Channel	20	0.090 at V_{GS} = 4.5 V	3.28
		0.110 at V_{GS} = 2.5 V	2.13
		0.130 at V_{GS} = 1.8 V	1.50
P-Channel	- 20	0.155 at V_{GS} = - 4.5 V	- 2.80
		0.190 at V_{GS} = - 2.5 V	- 1.81
		0.220 at V_{GS} = - 1.8 V	- 1.15

FEATURES

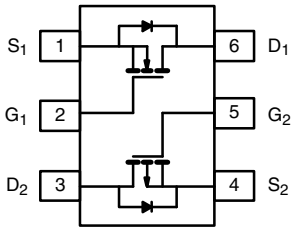
- **Halogen-free According to IEC 61249-2-21 Definition**
- Trench Power MOSFETs: 1.8 V Rated
- Thermally Enhanced SC-70 Package
- Fast Switching
- Compliant to RoHS Directive 2002/95/EC

Pb-free
RoHS COMPLIANT
HALOGEN FREE Available

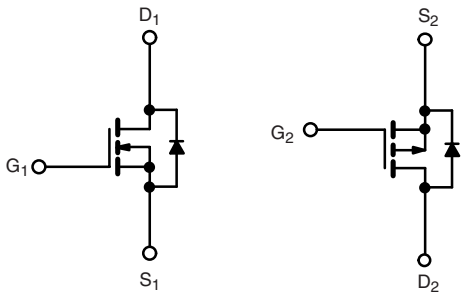
APPLICATIONS

- Load Switch for Portable Devices

SOT-363
SC-70 (6-LEADS)



Top View



ABSOLUTE MAXIMUM RATINGS T_A = 25 °C, unless otherwise noted							
			N-Channel		P-Channel		
Parameter		Symbol	5 s	Steady State	5 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	20		- 20		V
Gate-Source Voltage		V_{GS}	± 20		± 20		
Continuous Drain Current (T_J = 150 °C)[a]	T_A = 25 °C	I_D	3.28	3.03	- 2.80	- 2.58	A
	T_A = 85 °C		2.12	1.81	- 1.72	- 1.53	
Pulsed Drain Current		I_{DM}	9.5		- 8.5		
Continuous Source Current (Diode Conduction)[a]		I_S	2.61	2.48	- 1.61	-1.48	
Maximum Power Dissipation[a]	T_A = 25 °C	P_D	1.24	1.17	1.10	0.97	W
	T_A = 85 °C		0.88	0.75	0.66	0.5	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to 150				°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient[a]	t ≤ 5 s	R_{thJA}	130	170	°C/W
	Steady State		170	220	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	80	100	

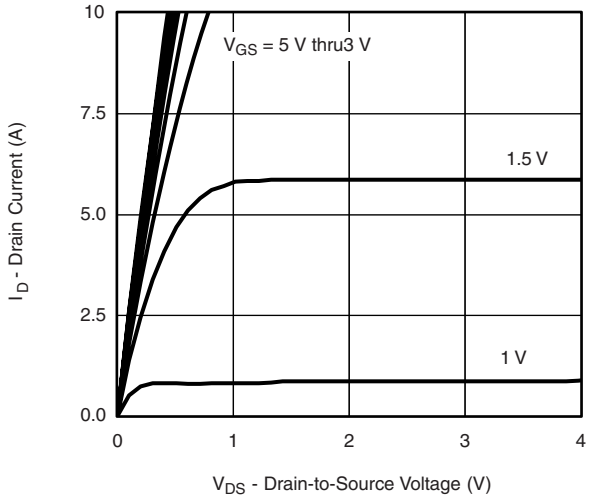
Notes:
a. Surface mounted on 1" x 1" FR4 board.

SPECIFICATIONS T_J = 25 °C, unless otherwise noted							
Parameter	**Symbol**	**Test Conditions**		**Min.**	**Typ.**	**Max.**	**Unit**
Static							
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 100 µA	N-Ch	0.45		1	V
		V_{DS} = V_{GS}, I_D = - 100 µA	P-Ch	- 0.45		1	
Gate-Body Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 8 V	N-Ch			± 100	nA
			P-Ch			± 100	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 16 V, V_{GS} = 0 V	N-Ch			1	µA
		V_{DS} = - 16 V, V_{GS} = 0 V	P-Ch			- 1	
		V_{DS} = 16 V, V_{GS} = 0 V, T_J = 85 °C	N-Ch			5	
		V_{DS} = - 16 V, V_{GS} = 0 V, T_J = 85 °C	P-Ch			- 5	
On-State Drain Current[a]	$I_{D(on)}$	V_{DS} ≥ 5 V, V_{GS} = 4.5 V	N-Ch	2			A
		V_{DS} ≤ - 5 V, V_{GS} = - 4.5 V	P-Ch	- 2			
Drain-Source On-State Resistance[a]	$R_{DS(on)}$	V_{GS} = 4.5 V, I_D = 2.55 A	N-Ch		0.090		Ω
		V_{GS} = - 4.5 V, I_D = - 1.85 A	P-Ch		0.155		
		V_{GS} = 2.5 V, I_D = 1.55 A	N-Ch		0.110		
		V_{GS} = - 2.5 V, I_D = - 1.35 A	P-Ch		0.190		
		V_{GS} = 1.8 V, I_D = 0.50 A	N-Ch		0.130		
		V_{GS} = - 1.8 V, I_D = - 0.50 A	P-Ch		0.220		
Forward Transconductance[a]	g_{fs}	V_{DS} = 10 V, I_D = 1.13 A	N-Ch		2.6		S
		V_{DS} = - 10 V, I_D = - 0.88 A	P-Ch		1.5		
Diode Forward Voltage[a]	V_{SD}	I_S = 0.48 A, V_{GS} = 0 V	N-Ch		0.8	1.2	V
		I_S = - 0.48 A, V_{GS} = 0 V	P-Ch		- 0.8	- 1.2	
Dynamic[b]							
Total Gate Charge	Q_g	N-Channel V_{DS} = 10 V, V_{GS} = 4.5 V, I_D = 2.55 A P-Channel V_{DS} = - 10 V, V_{GS} = - 4.5 V, I_D = - 0.88 A	N-Ch		1.25	2	nC
			P-Ch		1.2	1.8	
Gate-Source Charge	Q_{gs}		N-Ch		0.21		
			P-Ch		0.3		
Gate-Drain Charge	Q_{gd}		N-Ch		0.3		
			P-Ch		0.21		
Turn-On Delay Time	$t_{d(on)}$	N-Channel V_{DD} = 10 V, R_L = 20 Ω I_D ≅ 0.5 A, V_{GEN} = 4.5 V, R_g = 6 Ω P-Channel V_{DD} = - 10 V, R_L = 20 Ω I_D ≅ - 0.5 A, V_{GEN} = - 4.5 V, R_g = 6 Ω	N-Ch		15	25	ns
			P-Ch		18	30	
Rise Time	t_r		N-Ch		22	35	
			P-Ch		25	40	
Turn-Off Delay Time	$t_{d(off)}$		N-Ch		25	40	
			P-Ch		15	25	
Fall Time	t_f		N-Ch		12	20	
			P-Ch		12	20	
Reverse Recovery Time	t_{rr}	I_F = 0.48 A, dI/dt = 100 A/µs	N-Ch		30	60	
			P-Ch		30	60	

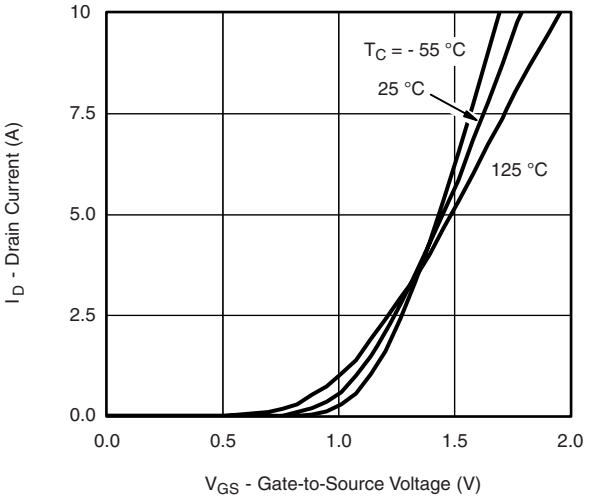
Notes:
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

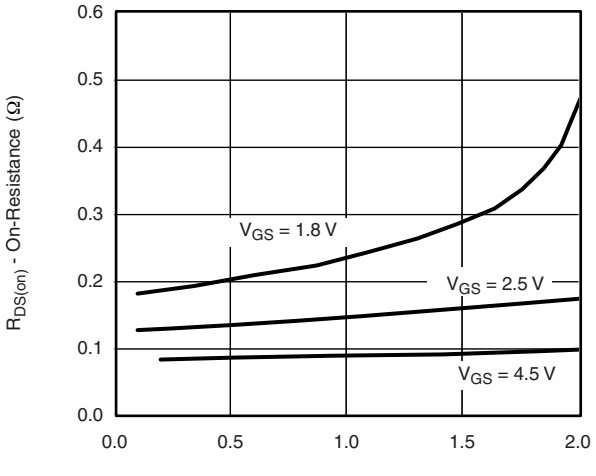
N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



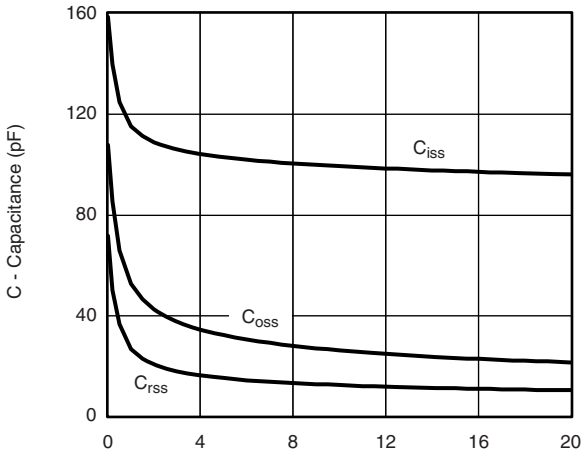
Output Characteristics



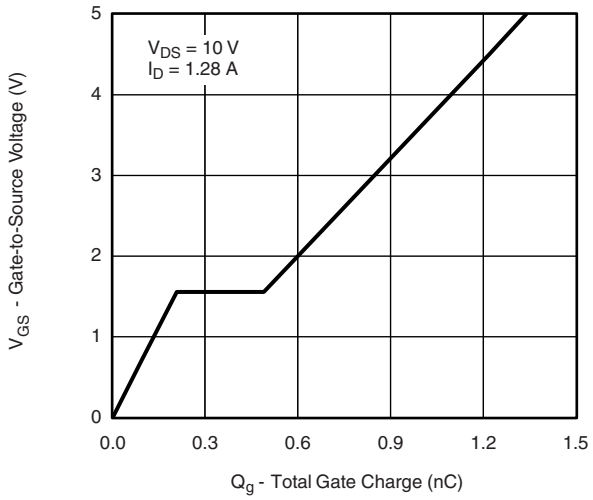
Transfer Characteristics



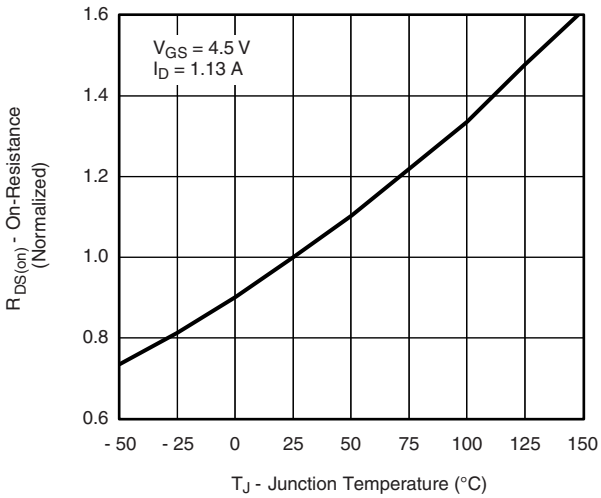
On-Resistance vs. Drain Current



Capacitance

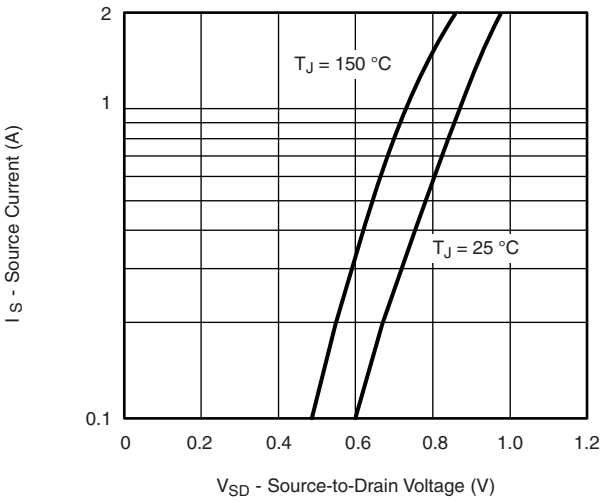


Gate Charge

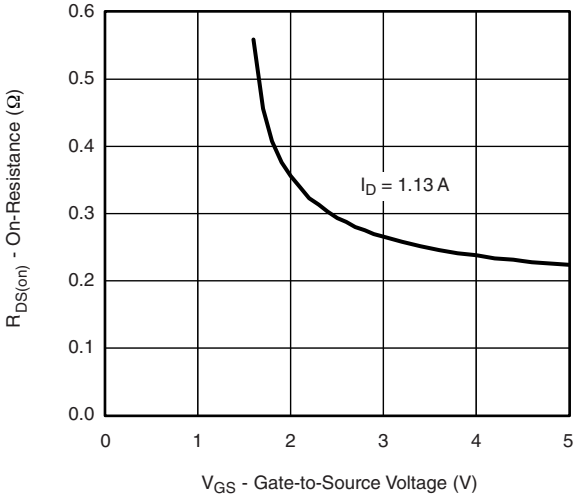


On-Resistance vs. Junction Temperature

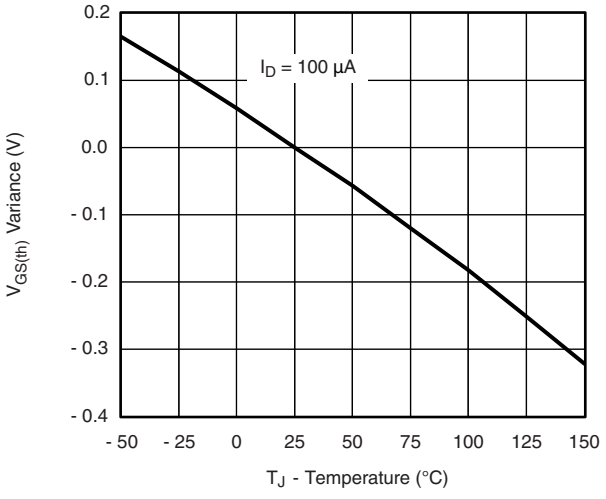
N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



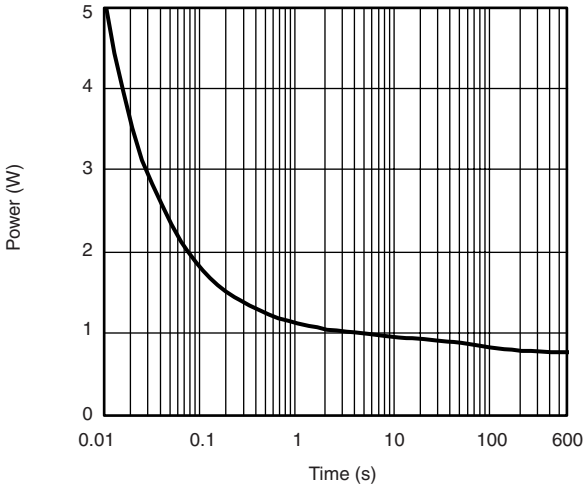
Source-Drain Diode Forward Voltage



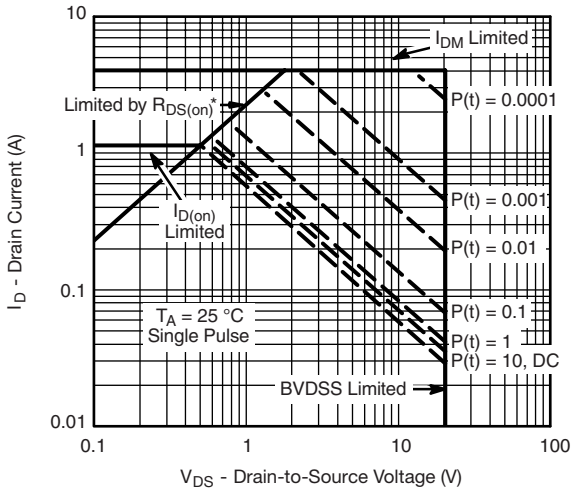
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



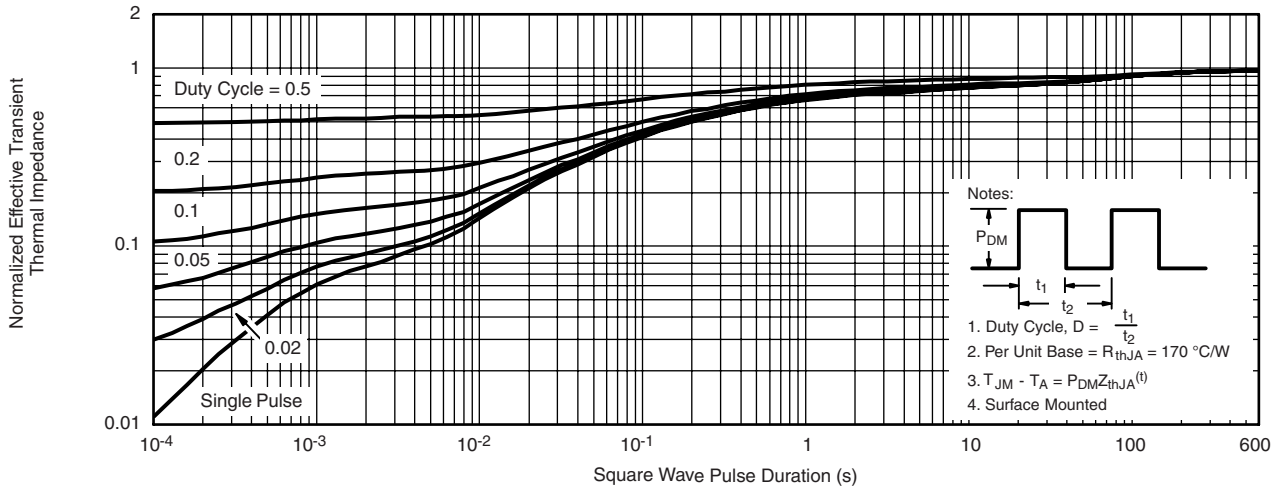
Single Pulse Power, Junction-to-Ambient



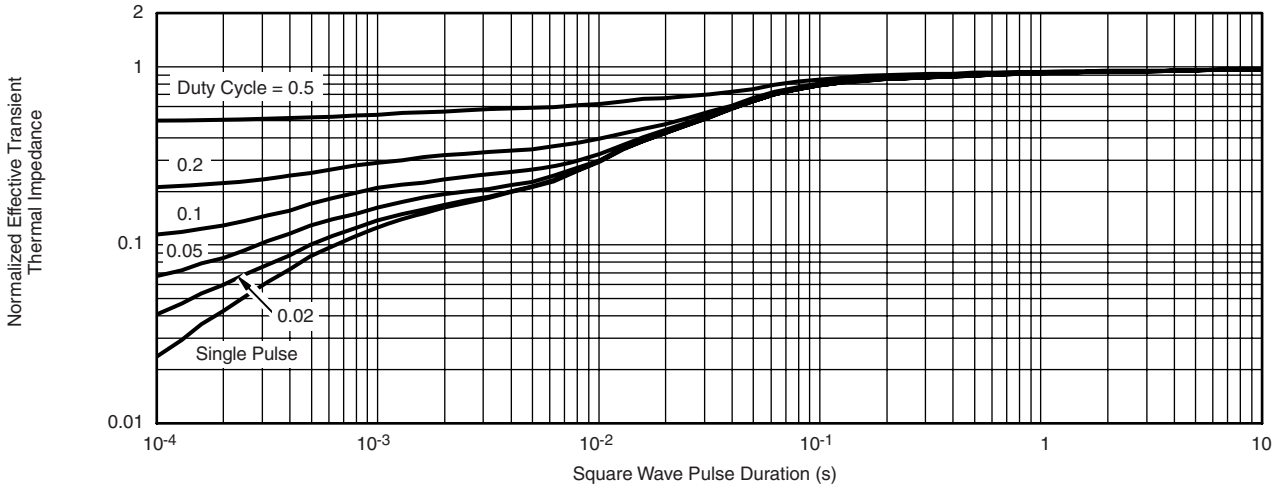
* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area, Junction-to-Ambient

N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

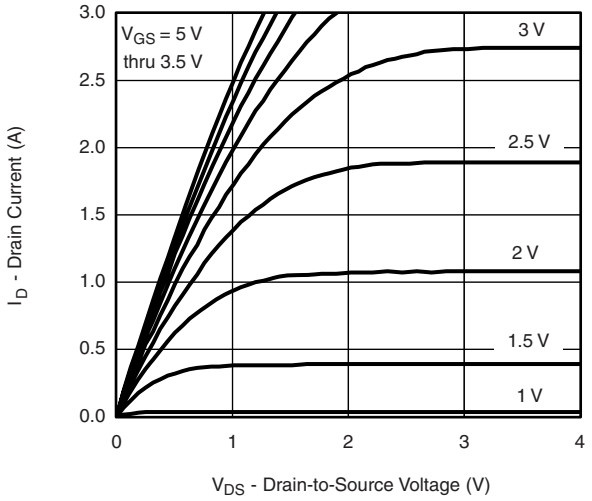


Normalized Thermal Transient Impedance, Junction-to-Ambient

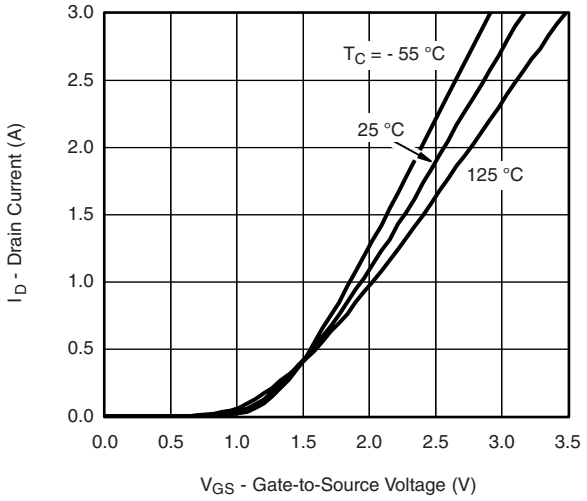


Normalized Thermal Transient Impedance, Junction-to-Foot

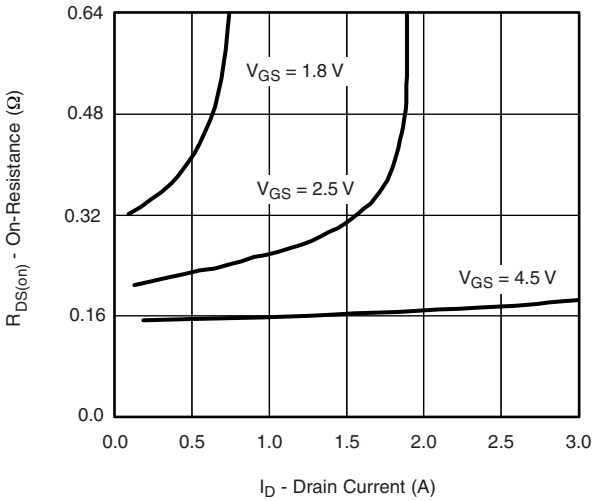
P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



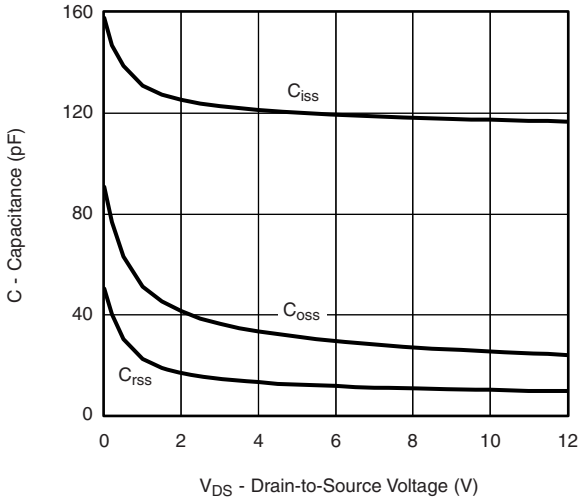
Output Characteristics



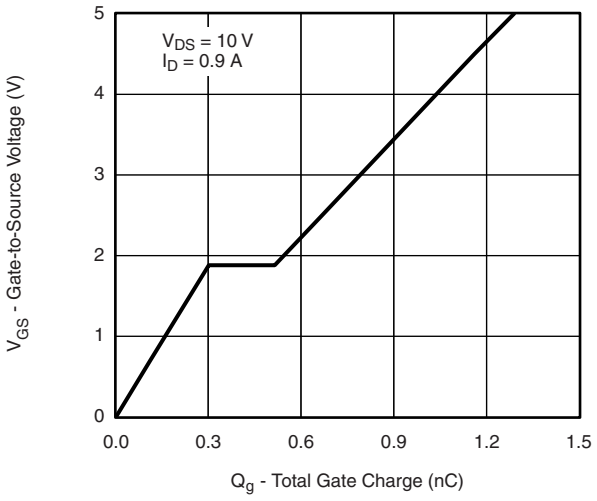
Transfer Characteristics



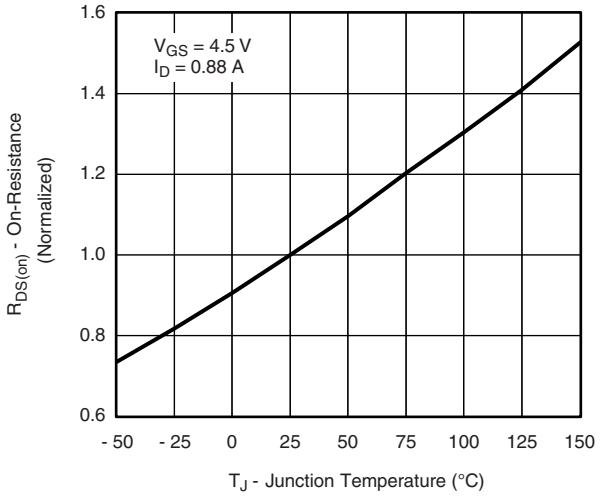
On-Resistance vs. Drain Current



Capacitance

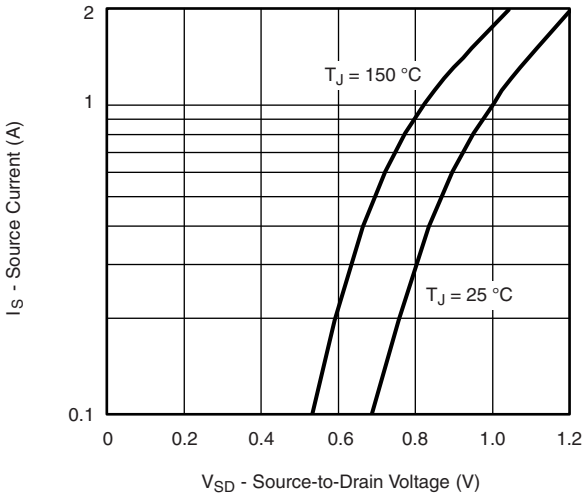


Gate Charge

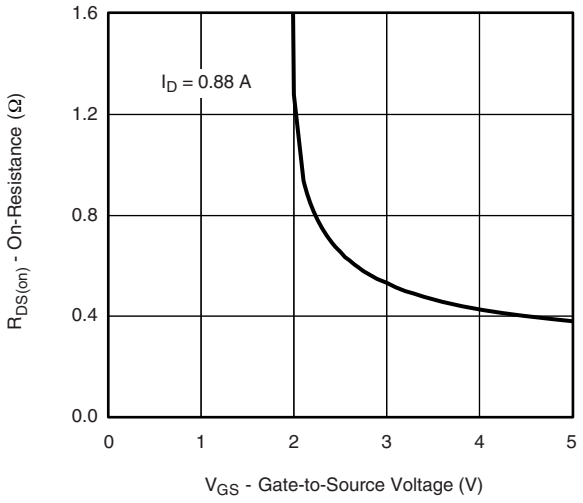


On-Resistance vs. Junction Temperature

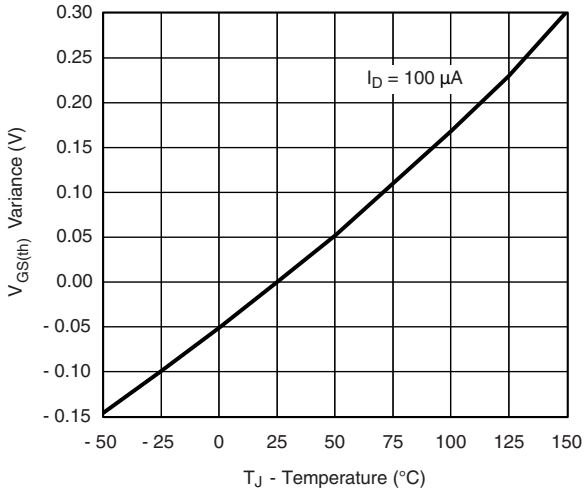
P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



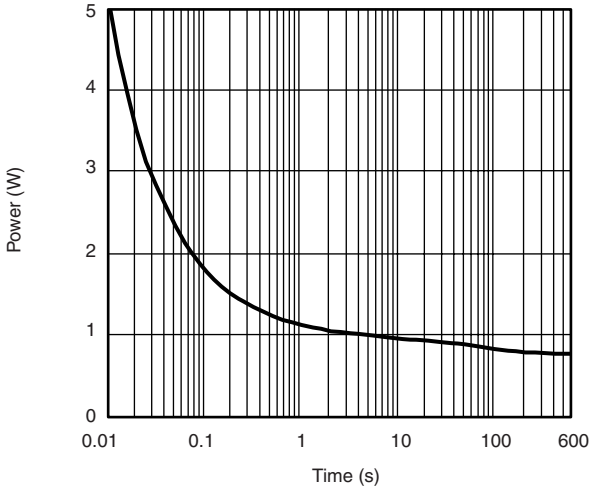
Source-Drain Diode Forward Voltage



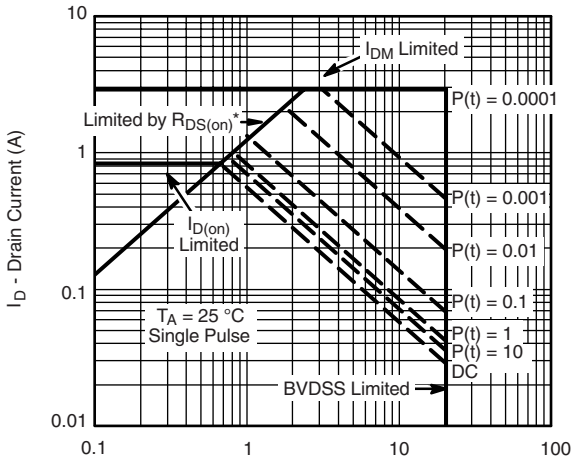
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



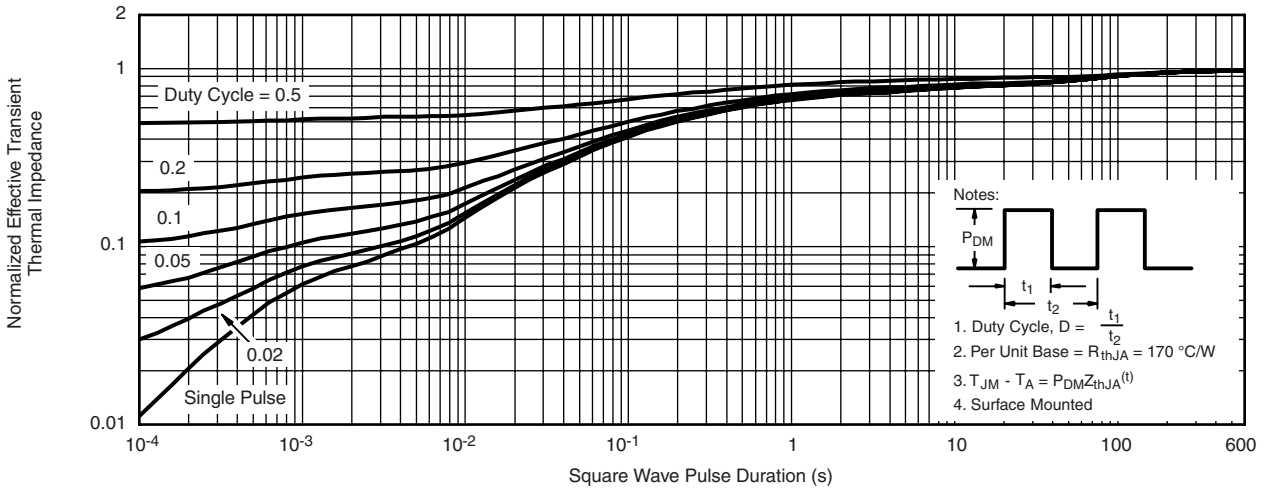
Single Pulse Power, Junction-to-Ambient



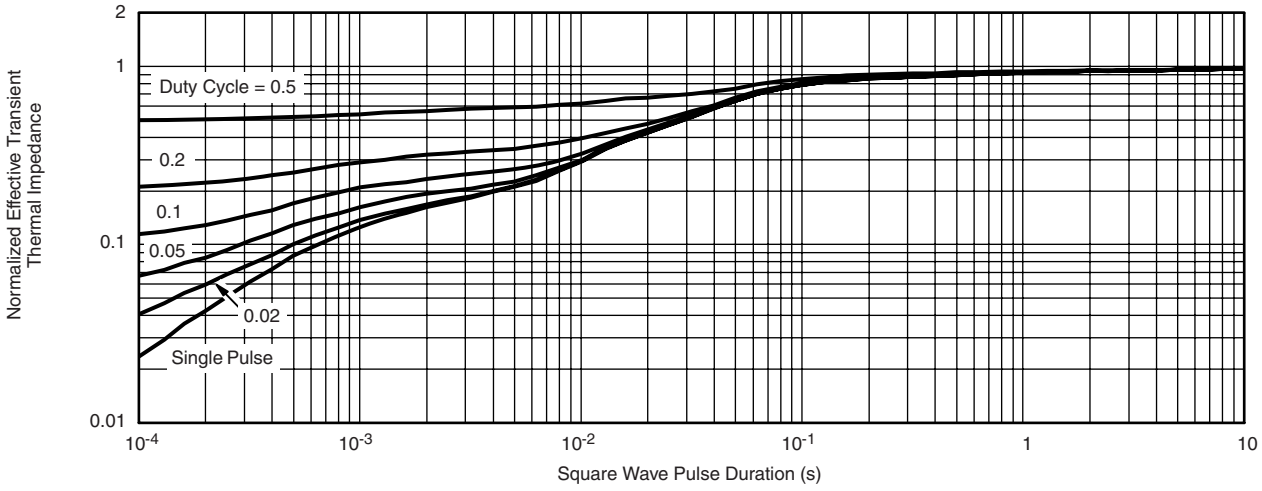
* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area, Junction-to-Ambient

P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

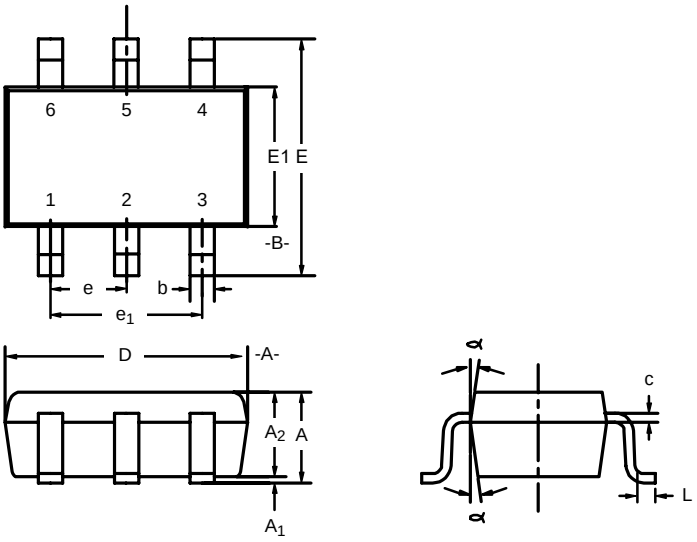


Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

SC-70: 6-LEADS



Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.90	–	1.10	0.035	–	0.043
A_1	–	–	0.10	–	–	0.004
A_2	0.80	–	1.00	0.031	–	0.039
b	0.15	–	0.30	0.006	–	0.012
c	0.10	–	0.25	0.004	–	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
E	1.80	2.10	2.40	0.071	0.083	0.094
E_1	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65BSC			0.026BSC		
e_1	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
α	7°Nom			7°Nom		

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Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

www.entegreci.com

Ürün kategorileri

Entegreden kapasitöre tüm elektronik komponent kategorileri.

Kategorilere göz atın

Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

www.entegreci.com | **destek@entegreci.com** | **0850 305 90 34**

Entegreci is an online electronic components store based in Türkiye. Search by manufacturer part number to see stock, prices and datasheets for integrated circuits, microcontrollers, transistors, passive components and connectors, or request a quote for parts that are not listed.

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